<u>MOSFET</u> – Power, Single, N-Channel

60 V, 1.2 mΩ, 287 A

NTMFS5C604NL

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	60	V
Gate-to-Source Voltage	e		V _{GS}	±20	V
Continuous Drain		$T_{C} = 25^{\circ}C$	۱ _D	287	А
Current R _{θJC} (Notes 1, 3)	Steady	T _C = 100°C		203	
Power Dissipation	State	$T_{C} = 25^{\circ}C$	PD	200	W
$R_{\theta JC}$ (Note 1)		T _C = 100°C		100	
Continuous Drain		T _A = 25°C	۱ _D	40	А
Current R _{θJA} (Notes 1, 2, 3)	Steady	T _A = 100°C		28	
Power Dissipation	State	T _A = 25°C	PD	3.9	W
$R_{\theta JA}$ (Notes 1 & 2)		T _A = 100°C		1.9	
Pulsed Drain Current	$T_A = 25^{\circ}C, t_p = 10 \ \mu s$		I _{DM}	900	А
Operating Junction and Storage Temperature			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			I _S	203	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 22 A)			E _{AS}	776	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	0.75	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	39	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

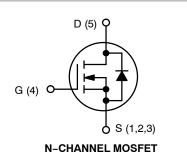
3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

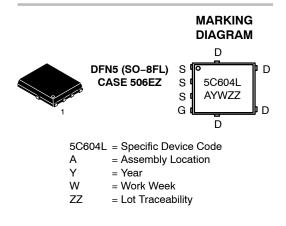


ON Semiconductor®

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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
60 V	1.2 mΩ @ 10 V	007 4
00 V	1.7 mΩ @ 4.5 V	287 A





ORDERING INFORMATION

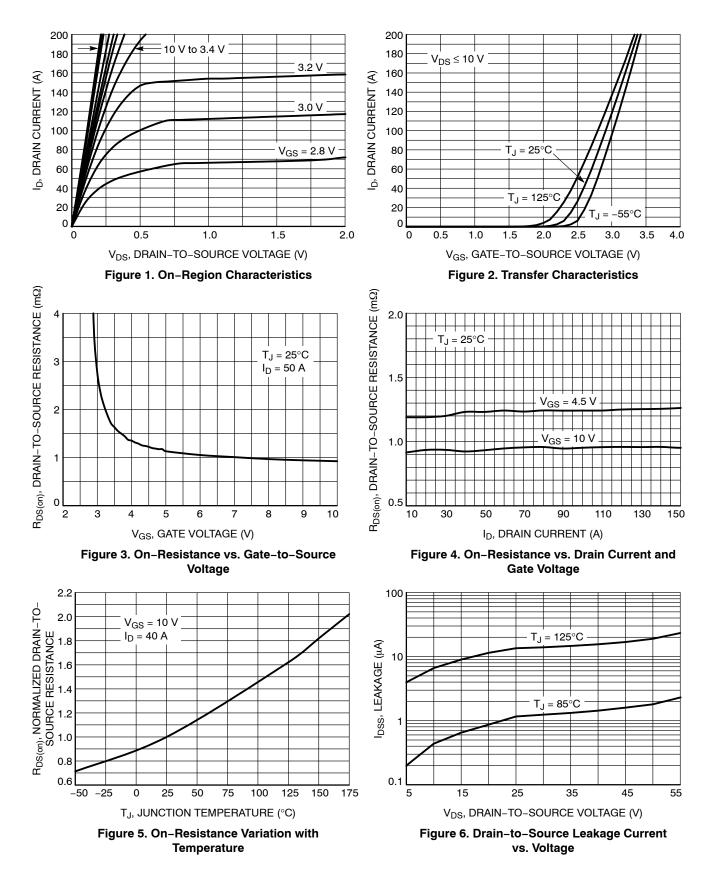
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

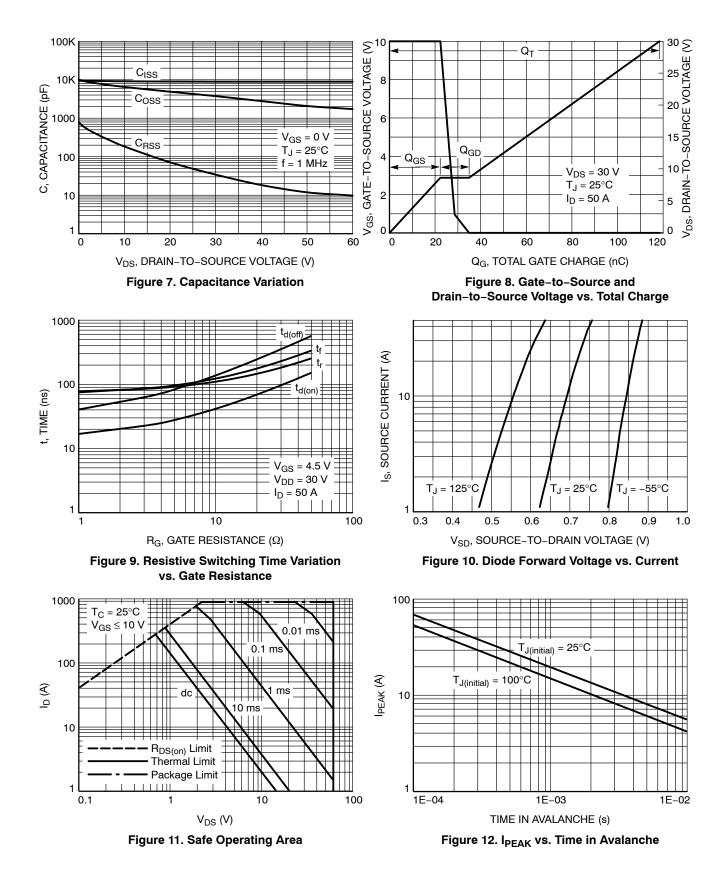
Parameter	Symbol	Test Cond	dition	Min	Тур	Max	Unit
OFF CHARACTERISTICS	-						
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 µA		60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J				22.9		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$			10	
		V _{DS} = 60 V	T _J = 125°C			250	μA
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS} = 20 V$				100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} = V _{DS} , I _D) = 250 μA	1.2		2.0	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-5.9		mV/°0
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 50 A		0.93	1.2	
		V _{GS} = 4.5 V	I _D = 50 A		1.25	1.7	mΩ
Forward Transconductance	9 _{FS}	V _{DS} = 15 V,	l _D = 50 A		180		S
Gate Resistance	R _G	T _A = 25	5°C			3.4	Ω
CHARGES AND CAPACITANCES							
Input Capacitance	C _{ISS}				8900		
Output Capacitance	C _{OSS}	$V_{GS} = 0 V$, f = 1 MHz, $V_{DS} = 25 V$ $V_{GS} = 4.5 V$, $V_{DS} = 30 V$; $I_D = 50 A$			3750		pF
Reverse Transfer Capacitance	C _{RSS}				40		
Total Gate Charge	Q _{G(TOT)}				52		
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 10 V, V_{DS} = 30 V; I_{D} = 50 A			120		1
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 4.5 V, V _{DS} = 30 V; I _D = 50 A			6.4		nC
Gate-to-Source Charge	Q _{GS}				21.4		v
Gate-to-Drain Charge	Q _{GD}				12.7		
Plateau Voltage	V _{GP}				2.8		
SWITCHING CHARACTERISTICS (Note	5)						
Turn–On Delay Time	t _{d(ON)}				32.9		
Rise Time	t _r	Vcs = 4.5 V. V	ne = 30 V.		29.9		1
Turn–Off Delay Time	t _{d(OFF)}	$V_{GS} = 4.5 \text{ V}, V_{DS} = 30 \text{ V}, \\ I_D = 50 \text{ A}, \text{ R}_G = 2.5 \Omega$			60.3		- ns
Fall Time	t _f				25.2		
DRAIN-SOURCE DIODE CHARACTER	STICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	T _J = 25°C		0.78	1.2	
	$V_{\rm GS} = 0.0$, $I_{\rm S} = 50$ A	T _J = 125°C		0.64		V	
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dIS/dt = 100 A/µs, I _S = 50 A			98		
Charge Time	t _a				45		ns
Discharge Time	t _b				53		1
Reverse Recovery Charge	Q _{RR}				190		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



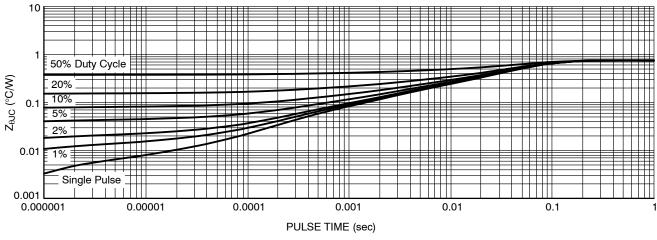


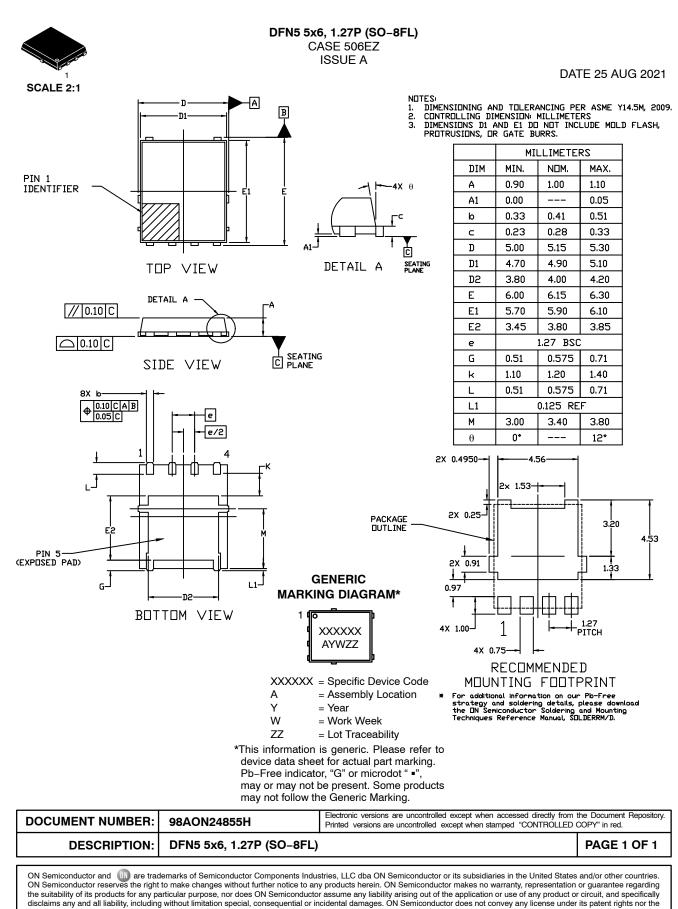
Figure	13.	Thermal	Characteristics
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DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NTMFS5C604NLT1G	5C604L	DFN5 (Pb–Free)	1500 / Tape & Reel
NTMFS5C604NLT3G	5C604L	DFN5 (Pb–Free)	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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